# Small Wonders in Our Future

#### Professor Umesh K. Mishra,

主流コロシーンティーンキャーオーションション

Director of the ONR Center for Advanced Nitride Electronics (CANE) and the AFOSR Center for Radiation Hard Physics

University of California, Santa Barbara

# Technology: The (Bad?) Answer to Society's Needs

公开的中于常言之后自己

#### MAXIMIZE COMPUTING POWER

- For geeks it provides the means of solving complex problems
- For non-geeks (engineers?) It enhances the quality of life
  - Computer-controlled transportation (higher reliability, better ride)
  - Home entertainment (SONY play station)
  - Predicting weather



#### ENHANCE COMMUNICATIONS

- Voice communications over land lines is "almost-free,"
  - Wireless communications is increasingly the norm,
- The internet has become integral in the life of the below 25 crowd,
  Streaming video

#### ENHANCE ENTERTAINMENT

- Complex video games
- High Definition Television
  - High Density DVD







# The Possibilities of the Very Small: Feynman said it first.....

上十一次在于于古主之口的一个

'I would like to describe a field, in which little has been done, but in which an enormous amount can be done in principle.... manipulating and controlling things on a small scale'

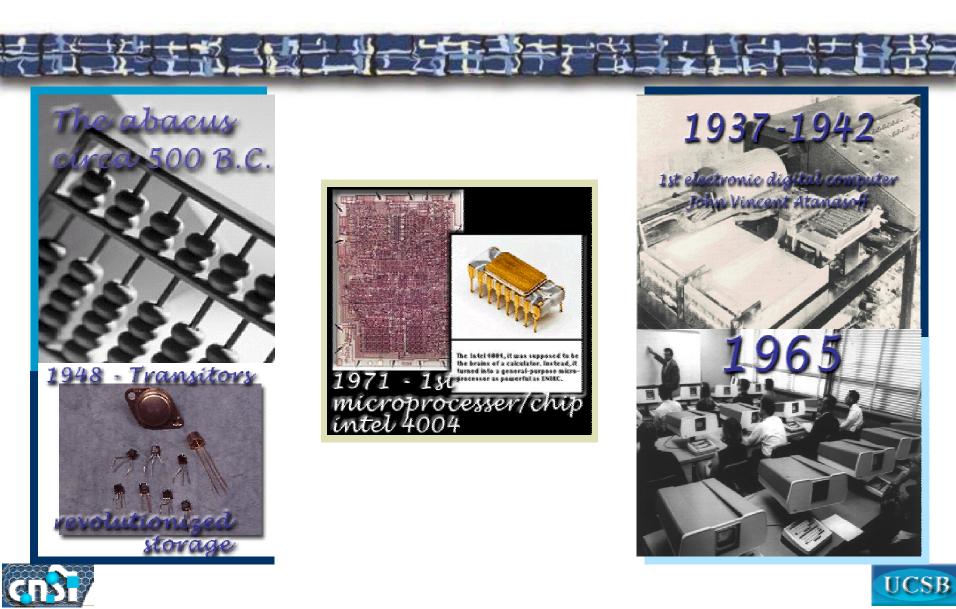
Richard Feynman, Caltech 1959 'There's Plenty of Room at the Bottom'

- Higher density of information: scaling down computer size
- 'New physics': atoms on a small scale behave like *nothing* on the large scale
- Formation of 'micromachines': machines that build machines
- Creation of 'designer materials'

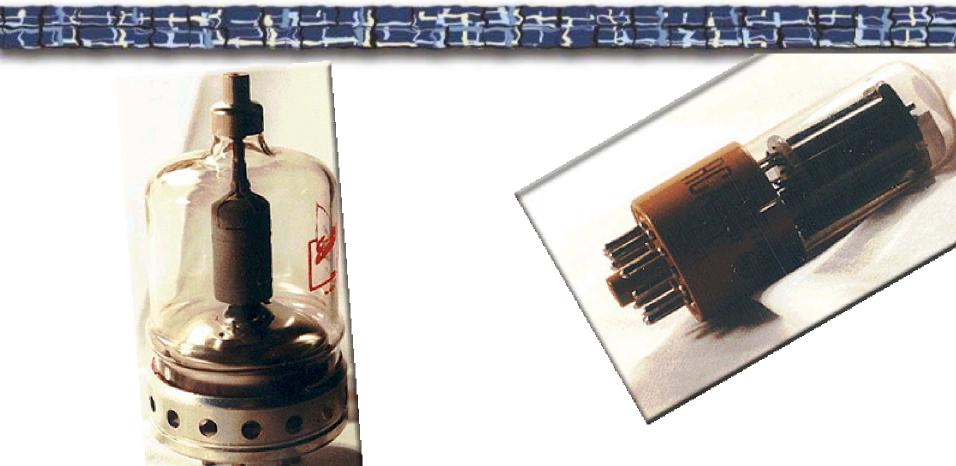




### Just One Small Example of Size...



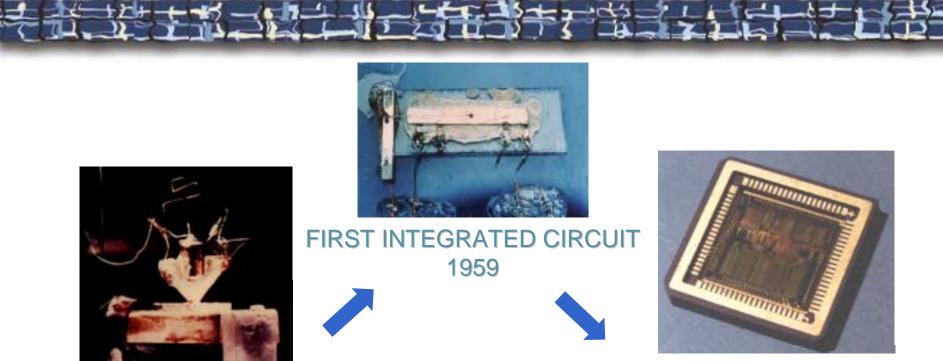
## History of Computing







# Higher Density Electronic Information



FIRST TRANSISTOR 1948 MICROPROCESSOR CHIP

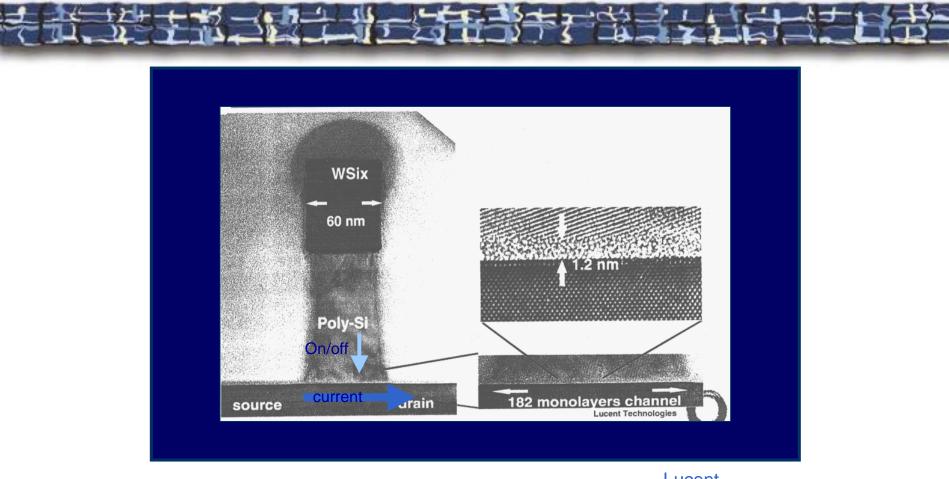
Scaling down to smaller switch sizes means more compact, lower cost computation, and information transfer



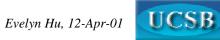
Evelyn Hu, 12-Apr-01



# Today's Transistor

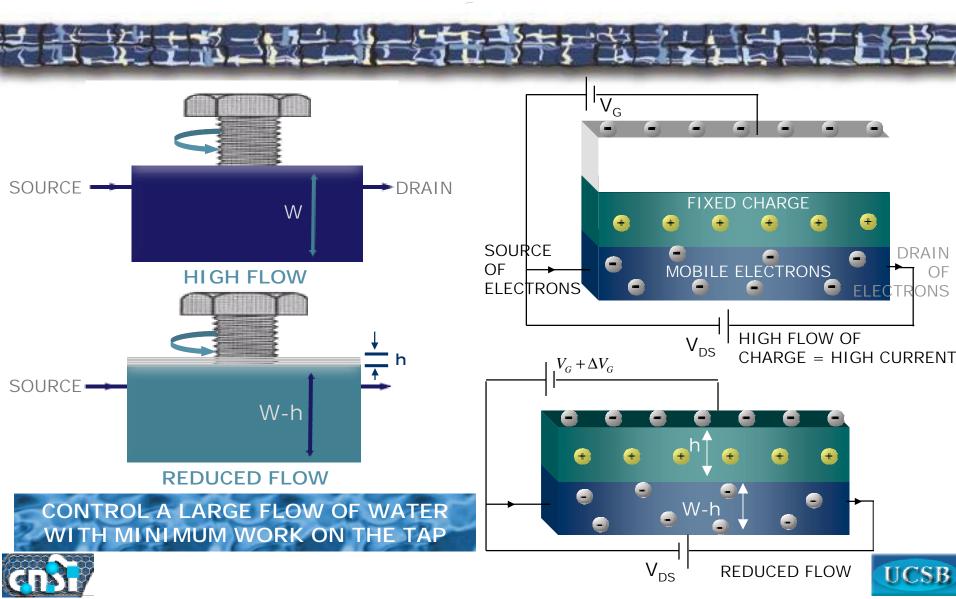


Lucent courtesy R.E. Howard





#### A Miraculous Engine – The Transistor THE ENGINE OF THE SEMICONDUCTOR



#### Moore's Law

UCSB

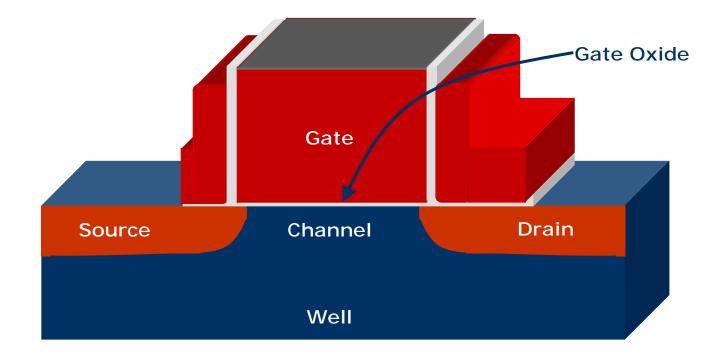
# 老士学主教之后于于法学生学生之后学生的学生

- Doubling of number of transistors per integrated circuit every 18- 24 months
  - First observed in 1965
- This expectation has driven Intel's research, development, and investments for the last 3 decades
  - Has enabled the incredible progress of the electronics industry



# What is a MOS Transistor?

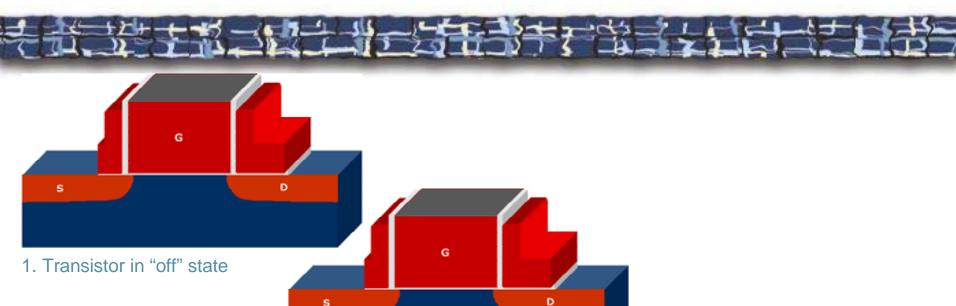
## 老台、地主教之论之外一台在当中于这三之后的一台







#### How Does a MOS Transistor Work?



2. Applying a voltage  $(V_T)$  to the gate "inverts" the channel region, creating an electrical path between the source and drain

3. Applying a voltage to the drain pulls current-carriers across the channel, creating the drive current  $(I_D)$ .

G

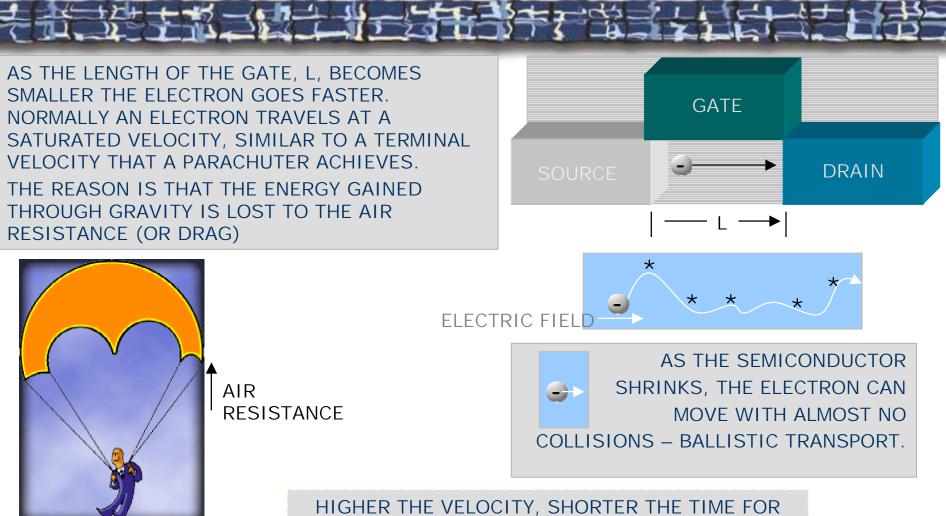
s

D

UCSB



#### Why Should We Want to Shrink Dimensions in Transistors 1. Faster Transistors



CINST/

🔪 GRAVITY

HIGHER THE VELOCITY, SHORTER THE TIME FOR ELECTRONS TO TRANSIT FROM SOURCE TO DRAIN; FASTER THE TRANSISTOR

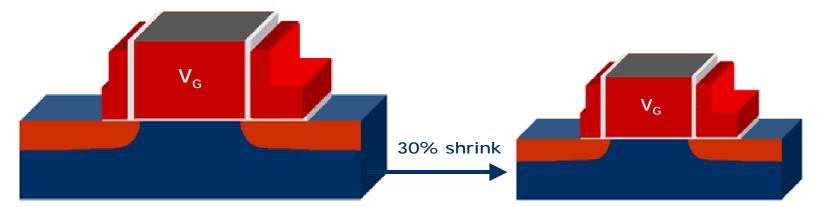


## **Transistor Scaling**



- The goal is to create smaller and faster transistors while retaining high level of performance.
- 30% linear shrink yields ½ transistor area

Transistor count doubles every two years







# Moore's Law Is Driven by Lithography

老台、建士都二位士者一位在当寺子馆主法上自己主任者

- 1960's Contact printing
- 1970's Projection printing
- 1980's Wafer steppers, 436nm
- 1990's Wafer scanners, 365nm, 248nm
- 2000's 193nm, 157nm, EUV ...





# So, why does scaling help?

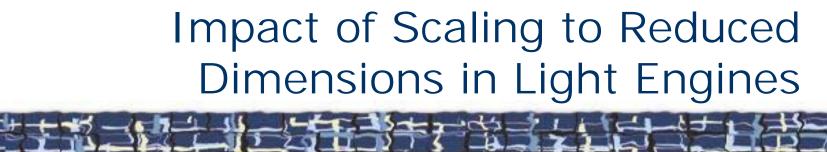
老台兰建主教之论主义于法王学于常主主任学



- Imagine a billiards table where the balls were electrons and the pockets were holes
- As the table is shrunk the probability of the ball dropping in a pocket (an electron meeting a hole) increases.
- When the size of the table is the size of the pocket (my kind of billiard table) the chance  $\rightarrow$  1

#### **REDUCED SIZE GIVES ENHANCED LIGHT OUT**





VOICE AND DATA ARE BEING CARRIED INCREASINGLY BY LASERS OVER OPTICAL FIBERS (AT THE EXPENSE OF

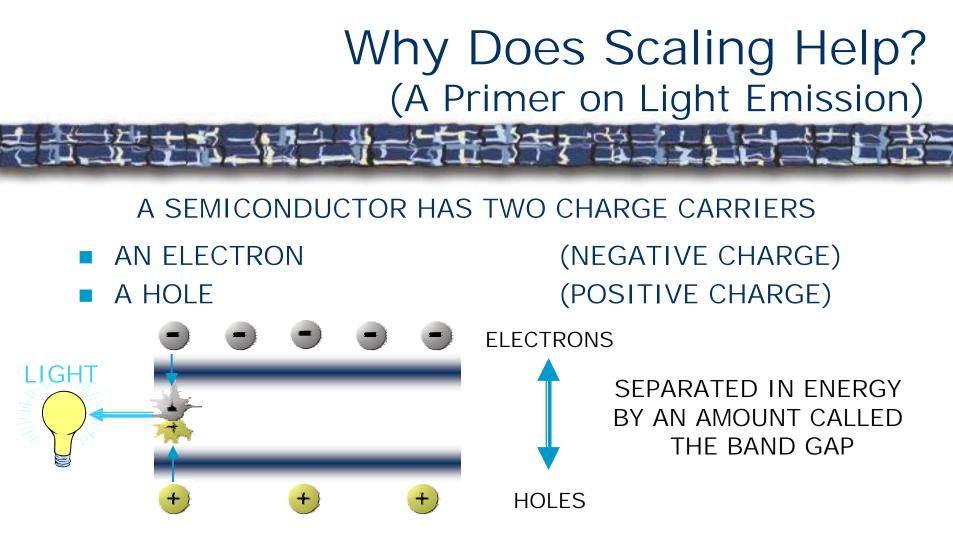
SATELLITES)



- LIGHT EMITTING DIODES ARE GETTING INCREASINGLY BRIGHTER, CHALLENGING CONVENTIONAL LIGHT BULBS FOR ILLUMINATION
- SHORT WAVELENGTH LASERS (CURRENTLY RED AND IN THE FUTURE BLUE) ARE MAKING STORAGE MORE DENSE AND MORE AFFORDABLE







ELECTRONS AND HOLES ATTRACT EACH OTHER AND WHEN THEY MEET THEY ANNIHILATE EACH OTHER AND THE ENERGY IS RELEASED AS LIGHT



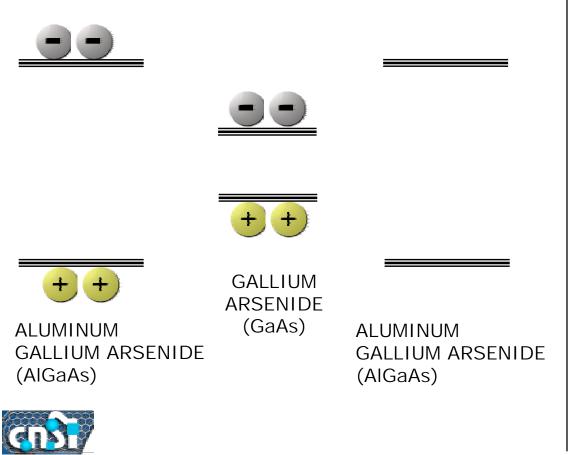
(THE RELEASE OF ENERGY BY ELECTRONS IS HOW X-RAYS ARE ALSO GENERATED)



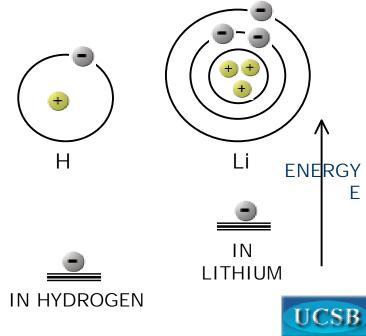
### Scaling Lasers – Quantum Well Lasers

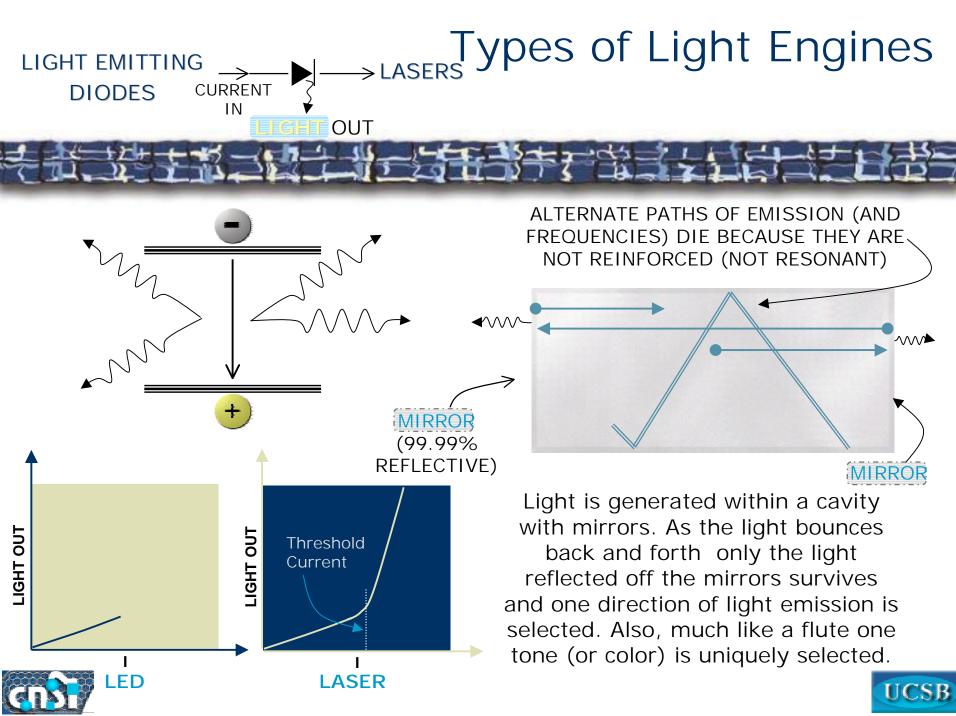
老台、楚主教之母生出一法任书于王宝之上自己主任书

#### MATERIALS WITH DIFFERENT BAND GAPS HAVE ELECTRONS (AND HOLES) AT DIFFERENT ENERGIES



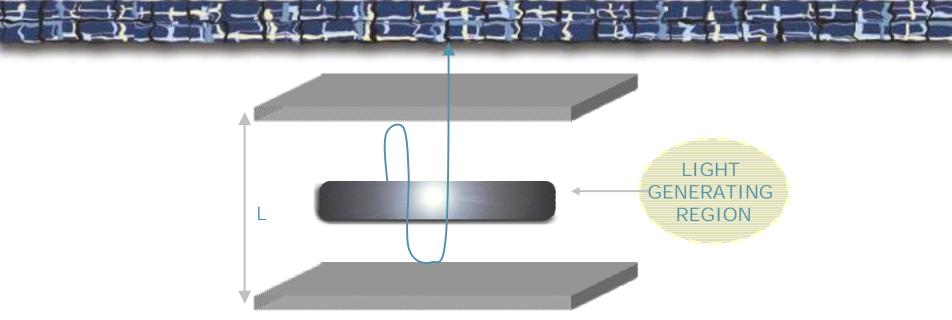
This is analogous to, say, electrons in the hydrogen atom (which has one electron) and lithium (which has three).



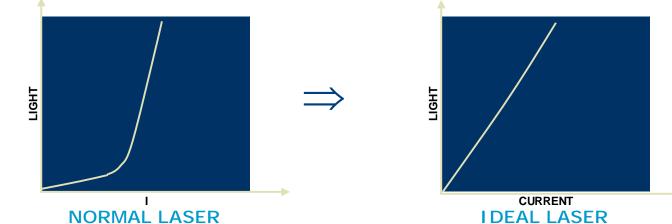


#### Making the Laser Better by Shrinking the Cavity LIGHT IN ONE DIRECTION AND AT ONE OLOR (LASER) LIGHT L LIGHT IN **REDUCES AS** GOOD THE CAVITY ALL DIRECTIONS LIKE AN LED **SHRINKS** RESOLVE CAL THIS WITH A **REDUCED CAVITY** 'n **REDUCES THE** BAD CAVITY LIGHT OUT UCSB

## Vertical Cavity Surface Emitting Laser (VCSEL)

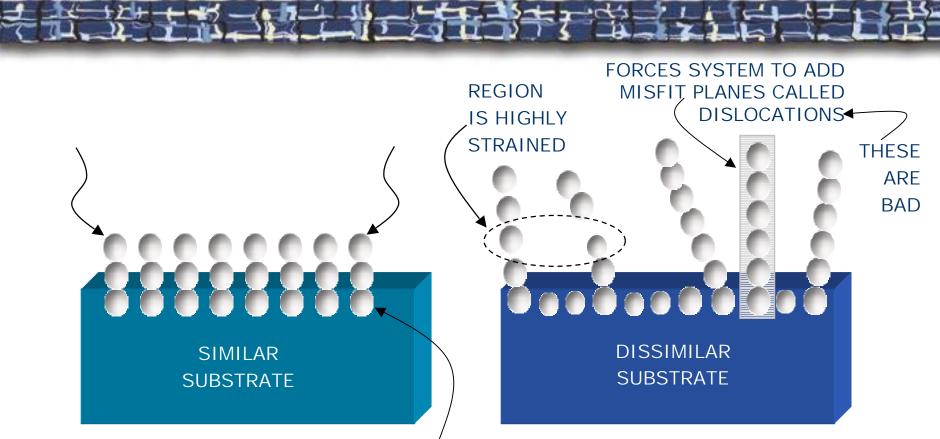


NOW THE CAVITY LENGTH L CAN BE REDUCED WITHOUT SACRIFICING LIGHT OUT





# The Problem with GaN No Substrate to Grow On



THE ATOMS OF THE SUBSTRATE PROVIDE A TEMPLATE TO GROW MATERIAL ON TOP, WITH THE GROWING ATOMS LINING UP WITH OR BONDING TO THE SUBSTRATE ATOMS HIS IS CALLED EPITAXY.





- GALLIUM NITRIDE HAS A VERY LARGE BAND GAP (3.4 Ev) WHICH ALLOWS IT TO SUSTAIN LARGE ELECTRIC FIELDS. IT WILL PROVIDE TECHNOLOGY FOR THE WIRELESS BASE STATIONS AND RADARS OF TOMORROW (BUT THAT'S A DIFFERENT BORING TALK)
- GALLIUM NITRIDE WHEN MIXED WITH INDIUM AND ALUMINUM TO FORM A FAMILY OF MATERIALS INCLUDING: ALUMINUM GALLIUM NITRIDE (AIGAN) AND INDIUM GALLIUM NITRIDE (InGaN) CAN EMIT LIGHT ACROSS THE FULL VISIBLE SPECTRUM

(THAT'S THE SUBJECT OF THIS BORING TALK)





# The Concept of Doping



IF YOU WANT ELECTRONS YOU SUBSTITUTE A SILICON ATOM (WHICH HAS 4 AVAILABLE ELECTRONS) WITH, SAY PHOSPHOROUS (WHICH HAS 5 AVAILABLE ELECTRONS). THE EXTRA ELECTRON IS GIVEN TO THE CRYSTAL.

 MAXIMUM DOPING ALLOWED BY THE CRYSTAL IS REPLACING 1 IN 100 ATOMS.

THE NUMBER OF ATOMS IN Si IS 10<sup>22</sup>/CM<sup>3</sup>.

THE NUMBER OF DOPANTS IS 10<sup>20</sup>/CM<sup>3</sup>.

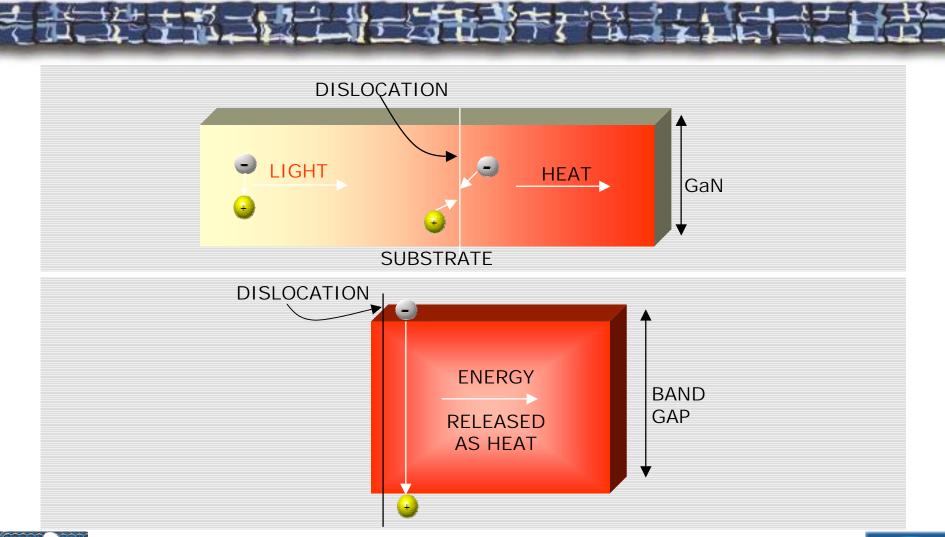
THE DISTANCE BETWEEN DOPANTS IS 5NM TOO LARGE!

WANT ELECTRONS TO BE NOT LIMITED BY NUMBER OF DOPANTS



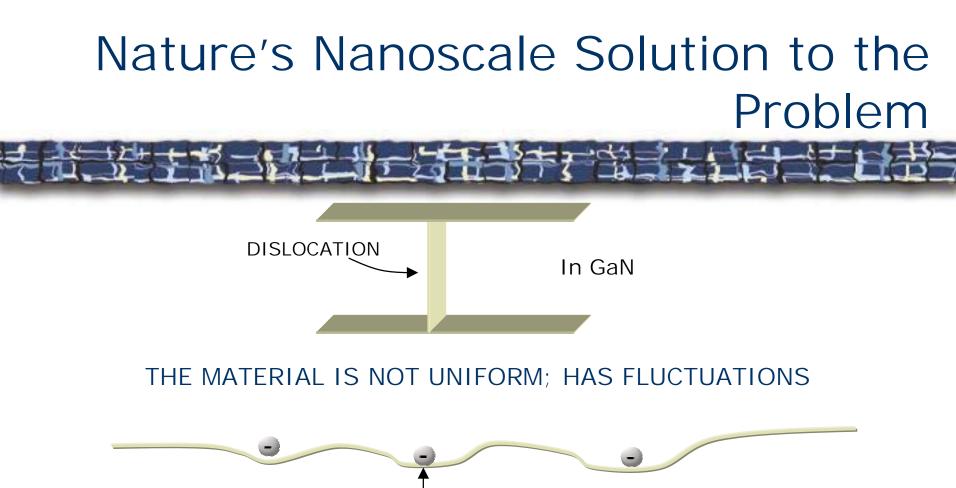


## Dislocations are Non-Radiative Regions



UCSB



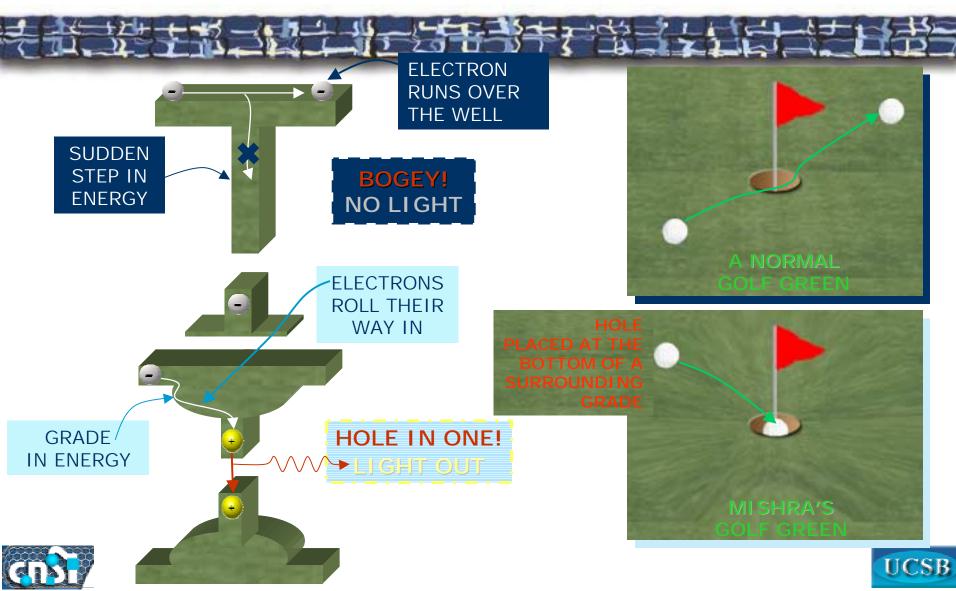


ELECTRONS AND HOLES COLLECT IN ENERGY WELLS DRAWN AWAY FROM DISLOCATIONS PRODUCING LIGHT NOT HEAT

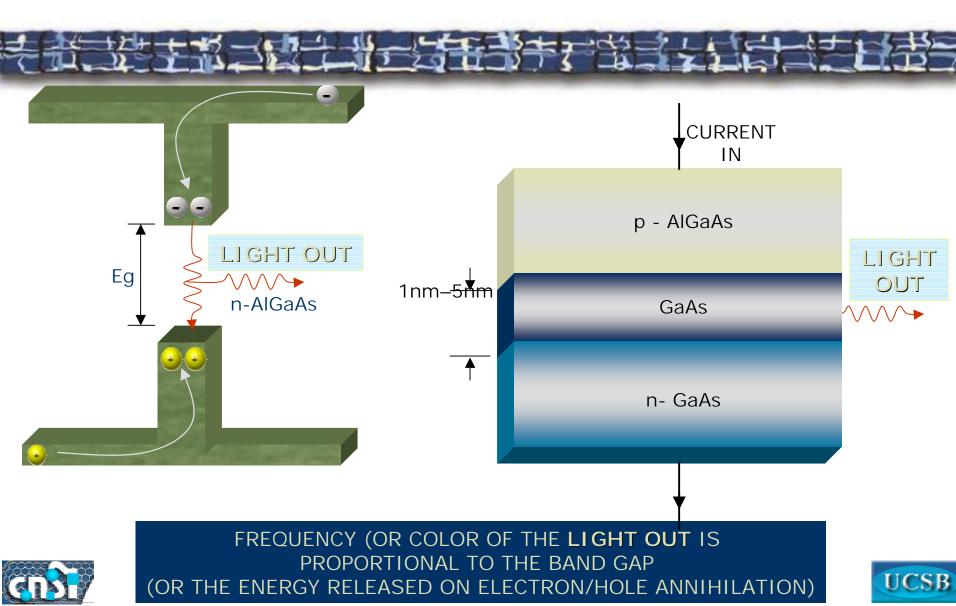




## Need for Engineering New Solutions When You Shrink Dimensions



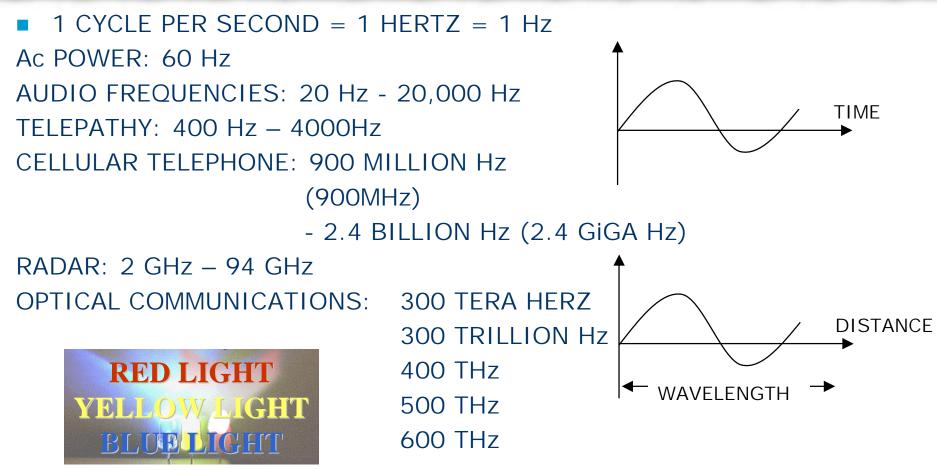
## Quantum Well Lasers



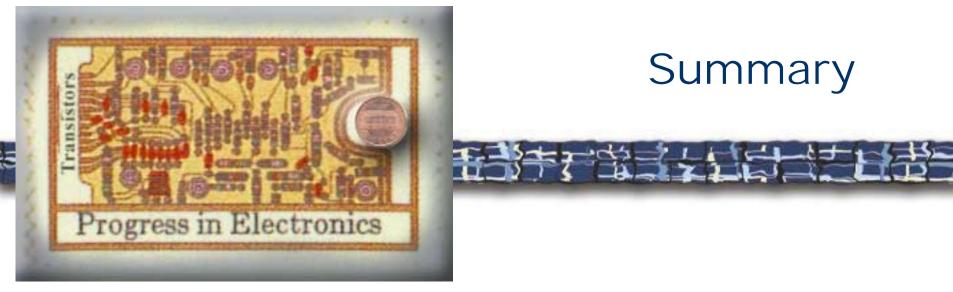
# Let's Get Calibrated

UCSB









SCALING DIMENSIONS HAVE LED TO ENHANCED PERFORMANCE AT A MUCH REDUCED COST 400 MILLION TRANSISTORS PENTIUM 4: COST: \$400

BUYING 1000 TRANSISTORS FOR \$.01



- NEW PRODUCTS KEEP EMERGING BECAUSE COMPUTING POWER IS NOW A COMMODITY; JUST ANOTHER PIECE IN YOUR LEGO SET
- AS DIMENSIONS SHRINK AND COMPLEXITY INCREASES, ACCESS (INPUT/OUTPUT) BECOMES A DOMINANT CONSIDERATION
- WE ARE NOW TRULY LIMITED BY OUR IMAGINATION (PLUS AS ALWAYS EXTENT OF SCIENTIFIC KNOWLEDGE AND MONEY).



